

# SKiiP 03NAC066V1



MiniSKiiP<sup>®</sup> 0

3-phase bridge rectifier +  
3-phase bridge inverter

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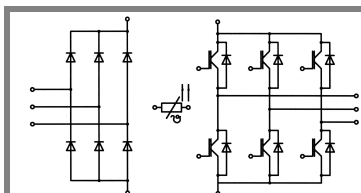
Target Data

## Features

- Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

## Typical Applications

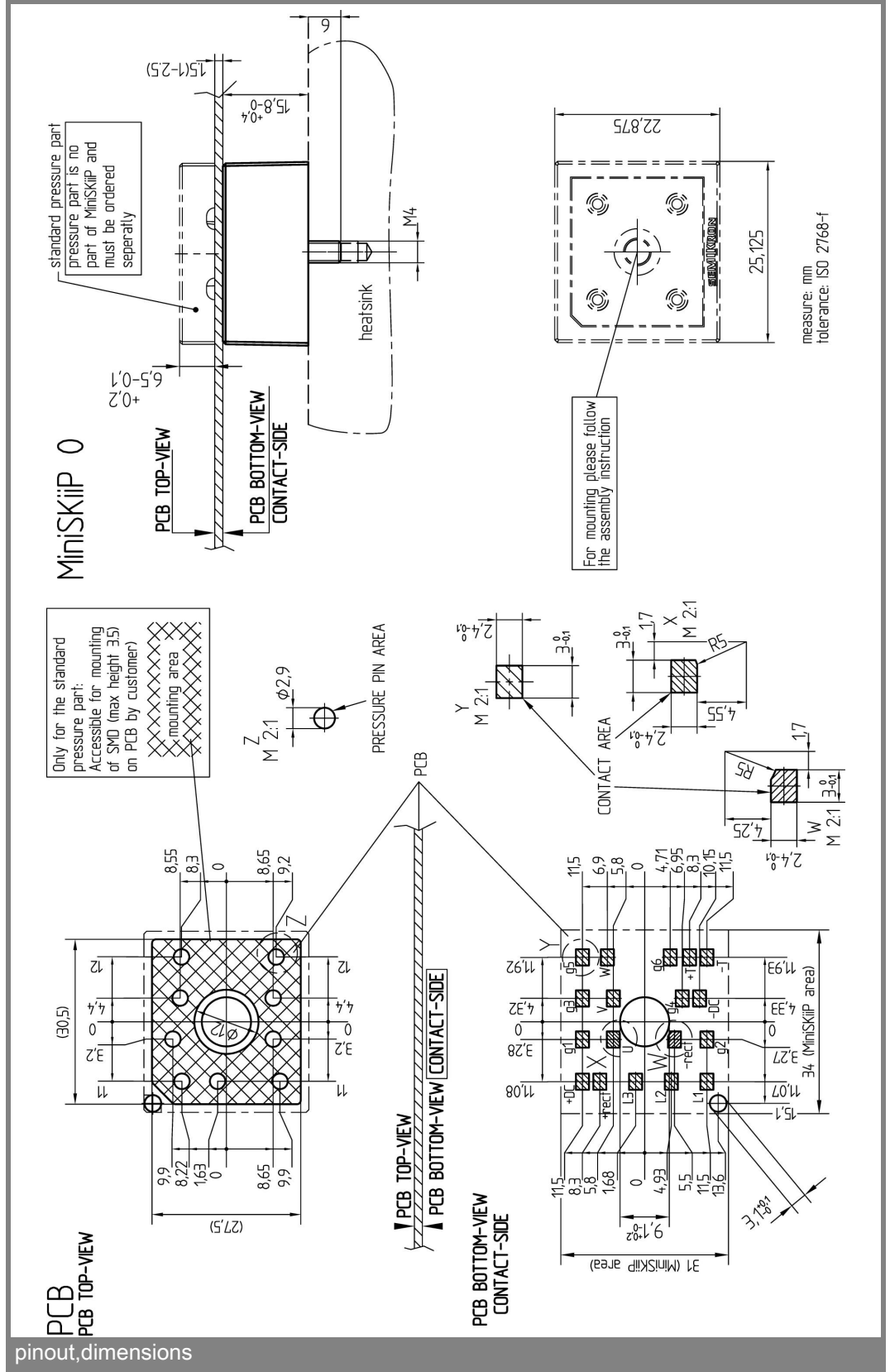
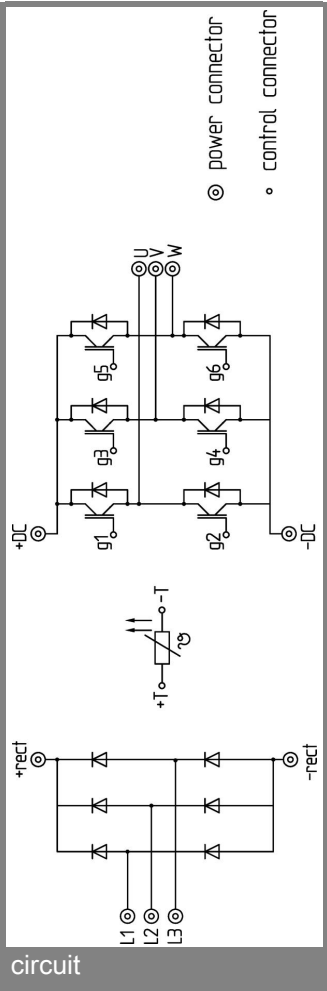
- Inverter up to 5,6 kVA
- Typical motor power 3,0 kW



NAC

Absolute Maximum Ratings		$T_s = 25\text{ }^\circ\text{C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT - Inverter, Chopper</b>			
$V_{CES}$		600	V
$I_C$	$T_s = 25\text{ (70) }^\circ\text{C}$	22 (17)	A
$I_{CRM}$	$T_s = 25\text{ (70) }^\circ\text{C}$ , $t_p \leq 1\text{ ms}$	23 (19)	A
$V_{GES}$		$\pm 20$	V
$T_j$		- 40 ... + 175	$^\circ\text{C}$
<b>Diode - Inverter, Chopper</b>			
$I_F$	$T_s = 25\text{ (70) }^\circ\text{C}$	20 (15)	A
$I_{FRM}$	$T_s = 25\text{ (70) }^\circ\text{C}$ , $t_p \leq 1\text{ ms}$	22 (18)	A
$T_j$		- 40 ... + 175	$^\circ\text{C}$
<b>Diode - Rectifier</b>			
$V_{RRM}$		800	V
$I_F$	$T_s = 70\text{ }^\circ\text{C}$	35	A
$I_{FSM}$	$t_p = 10\text{ ms}$ , sin 180 $^\circ$ , $T_j = 25\text{ }^\circ\text{C}$	220	A
$i^2t$	$t_p = 10\text{ ms}$ , sin 180 $^\circ$ , $T_j = 25\text{ }^\circ\text{C}$	240	A <sup>2</sup> s
$T_j$		- 40 ... + 150	$^\circ\text{C}$
$I_{tRMS}$	per power terminal (20 A / spring)	20	A
$T_{stg}$	$T_{op} \leq T_{stg}$	- 40 ... + 125	$^\circ\text{C}$
$V_{isol}$	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ }^\circ\text{C}$ , unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT - Inverter, Chopper</b>					
$V_{CEsat}$	$I_C = 15\text{ A}$ , $T_j = 25\text{ (125) }^\circ\text{C}$	1,1	1,45 (1,65)	1,85 (2,05)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 1\text{ mA}$		5,8		V
$V_{CE(TO)}$	$T_j = 25\text{ (150) }^\circ\text{C}$		0,9 (0,85)	1 (0,9)	V
$r_T$	$T_j = 25\text{ (150) }^\circ\text{C}$		40 (57)	60 (80)	m $\Omega$
$C_{ies}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		0,86		nF
$C_{oes}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		0,18		nF
$C_{res}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		0,12		nF
$R_{th(j-s)}$	per IGBT		1,78		K/W
$t_{d(on)}$	under following conditions		20		ns
$t_r$	$V_{CC} = 300\text{ V}$ , $V_{GE} = \pm 15\text{ V}$		30		ns
$t_{d(off)}$	$I_C = 15\text{ A}$ , $T_j = 125\text{ }^\circ\text{C}$		155		ns
$t_f$	$R_{Gon} = R_{Goff} = 22\text{ }\Omega$		40		ns
$E_{on}$	inductive load		0,55		mJ
$E_{off}$			0,24		mJ
<b>Diode - Inverter, Chopper</b>					
$V_F = V_{EC}$	$I_F = 15\text{ A}$ , $T_j = 25\text{ (125) }^\circ\text{C}$		1,4 (1,4)	1,7 (1,7)	V
$V_{(TO)}$	$T_j = 25\text{ (150) }^\circ\text{C}$		1 (0,9)	1,1 (1)	V
$r_T$	$T_j = 25\text{ (150) }^\circ\text{C}$		27 (33)	40 (47)	m $\Omega$
$R_{th(j-s)}$	per diode		2,46		K/W
$I_{RRM}$	under following conditions		20		A
$Q_{rr}$	$I_F = 15\text{ A}$ , $V_R = 300\text{ V}$		1,8		$\mu\text{C}$
$E_{rr}$	$V_{GE} = 0\text{ V}$ , $T_j = 125\text{ }^\circ\text{C}$		0,45		mJ
	$di_F/dt = 930\text{ A}/\mu\text{s}$				
<b>Diode - Rectifier</b>					
$V_F$	$I_F = 15\text{ A}$ , $T_j = 25\text{ }^\circ\text{C}$		1,1		V
$V_{(TO)}$	$T_j = 150\text{ }^\circ\text{C}$		0,8		V
$r_T$	$T_j = 150\text{ }^\circ\text{C}$		20		m $\Omega$
$R_{th(j-s)}$	per diode		1,5		K/W
<b>Temperature Sensor</b>					
$R_{ts}$	3 %, $T_r = 25\text{ (100) }^\circ\text{C}$		1000(1670)		$\Omega$
<b>Mechanical Data</b>					
w			35		g
$M_s$	Mounting torque	2		2,5	Nm



This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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